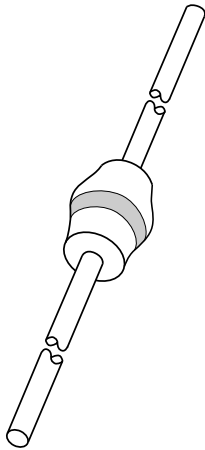


DATA SHEET



BYM26 series Fast soft-recovery controlled avalanche rectifiers

Product specification
Supersedes data of February 1994
File under Discrete Semiconductors, SC01

1996 May 24

Fast soft-recovery controlled avalanche rectifiers

BYM26 series

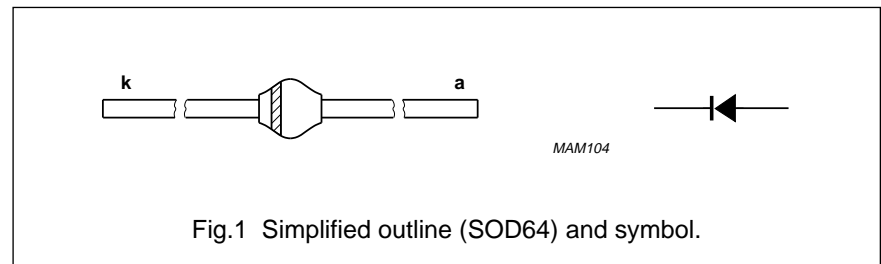
FEATURES

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Guaranteed avalanche energy absorption capability
- Available in ammo-pack
- Also available with preformed leads for easy insertion.

DESCRIPTION

Rugged glass SOD64 package, using a high temperature alloyed

construction. This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{RRM}	repetitive peak reverse voltage				
	BYM26A		–	200	V
	BYM26B		–	400	V
	BYM26C		–	600	V
	BYM26D		–	800	V
	BYM26E		–	1000	V
	BYM26F BYM26G		–	1200 1400	V V
V _R	continuous reverse voltage				
	BYM26A		–	200	V
	BYM26B		–	400	V
	BYM26C		–	600	V
	BYM26D		–	800	V
	BYM26E		–	1000	V
	BYM26F BYM26G		–	1200 1400	V V
I _{F(AV)}	average forward current	T _{tp} = 55 °C; lead length = 10 mm; see Figs 2 and 3; averaged over any 20 ms period; see also Figs 10 and 11	–	2.30	A
	BYM26A to E BYM26F and G		–	2.40	A
I _{F(AV)}	average forward current	T _{amb} = 65 °C; PCB mounting (see Fig.19); see Figs 4 and 5; averaged over any 20 ms period; see also Figs 10 and 11	–	1.05	A
	BYM26A to E BYM26F and G		–	1.00	A

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SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_{FRM}	repetitive peak forward current	$T_{tp} = 55\text{ °C}$; see Figs 6 and 7	–	19	A
	BYM26A to E		–	21	A
I_{FRM}	repetitive peak forward current	$T_{amb} = 65\text{ °C}$; see Figs 8 and 9	–	8.0	A
	BYM26F and G		–	8.5	A
I_{FSM}	non-repetitive peak forward current	$t = 10\text{ ms}$ half sine wave; $T_j = T_{j\text{ max}}$ prior to surge; $V_R = V_{RRM\text{ max}}$	–	45	A
E_{RSM}	non-repetitive peak reverse avalanche energy	$L = 120\text{ mH}$; $T_j = T_{j\text{ max}}$ prior to surge; inductive load switched off	–	10	mJ
T_{stg}	storage temperature		–65	+175	°C
T_j	junction temperature	see Figs 12 and 13	–65	+175	°C

ELECTRICAL CHARACTERISTICS

$T_j = 25\text{ °C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	forward voltage	$I_F = 2\text{ A}$; $T_j = T_{j\text{ max}}$; see Figs 14 and 15	–	–	1.34	V
	BYM26A to E		–	–	1.34	V
V_F	forward voltage	$I_F = 2\text{ A}$; see Figs 14 and 15	–	–	2.65	V
	BYM26F and G		–	–	2.30	V
$V_{(BR)R}$	reverse avalanche breakdown voltage	$I_R = 0.1\text{ mA}$				
	BYM26A		300	–	–	V
	BYM26B		500	–	–	V
	BYM26C		700	–	–	V
	BYM26D		900	–	–	V
	BYM26E		1100	–	–	V
	BYM26F		1300	–	–	V
BYM26G	1500	–	–	V		
I_R	reverse current	$V_R = V_{RRM\text{ max}}$; see Fig.16	–	–	10	μA
		$V_R = V_{RRM\text{ max}}$; $T_j = 165\text{ °C}$; see Fig.16	–	–	150	μA
t_{rr}	reverse recovery time	when switched from $I_F = 0.5\text{ A}$ to $I_R = 1\text{ A}$; measured at $I_R = 0.25\text{ A}$; see Fig.20	–	–	30	ns
			–	–	75	ns
			–	–	150	ns

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
C_d	diode capacitance	$f = 1 \text{ MHz}; V_R = 0 \text{ V};$ see Figs 17 and 18	–	85	–	pF
	BYM26A to C					
	BYM26D and E					
	BYM26F and G	–	65	–	pF	
$\left \frac{dI_R}{dt} \right $	maximum slope of reverse recovery current	when switched from $I_F = 1 \text{ A}$ to $V_R \geq 30 \text{ V}$ and $dI_F/dt = -1 \text{ A}/\mu\text{s};$ see Fig.21	–	–	7	A/ μs
	BYM26A to C					
	BYM26D and E					
	BYM26F and G	–	–	5	A/ μs	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th \text{ j-tp}}$	thermal resistance from junction to tie-point	lead length = 10 mm	25	K/W
$R_{th \text{ j-a}}$	thermal resistance from junction to ambient	note 1	75	K/W

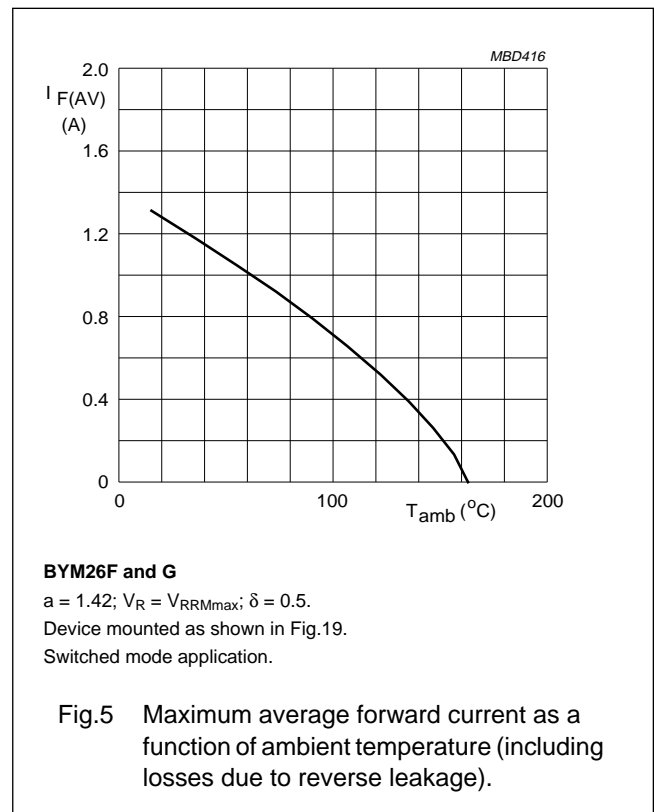
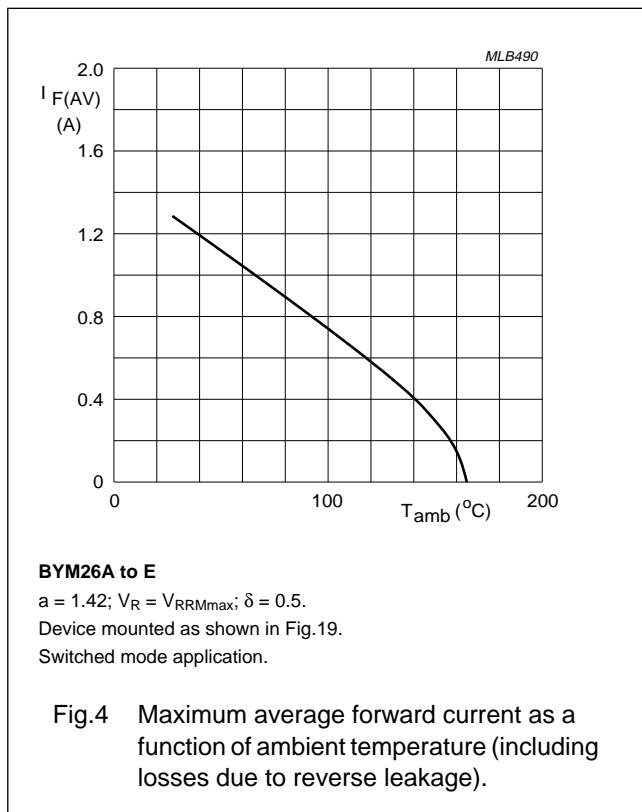
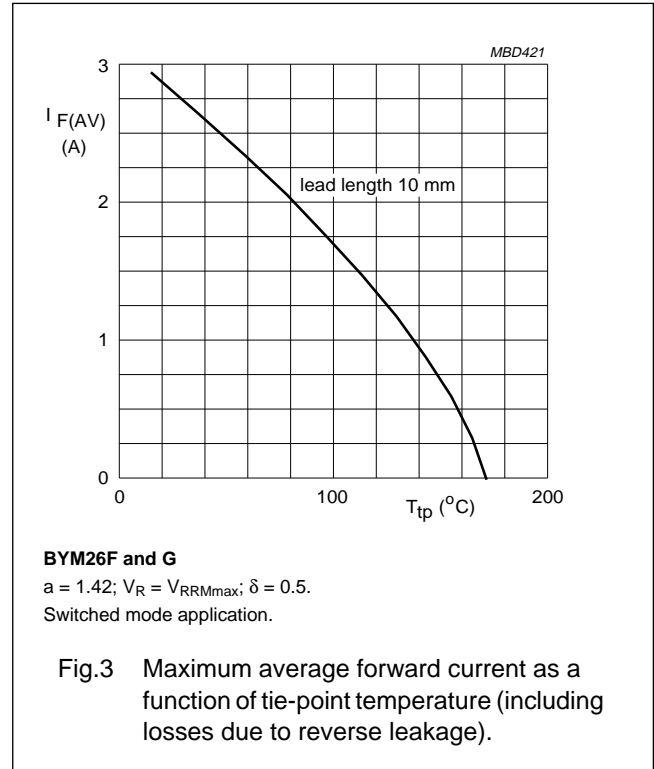
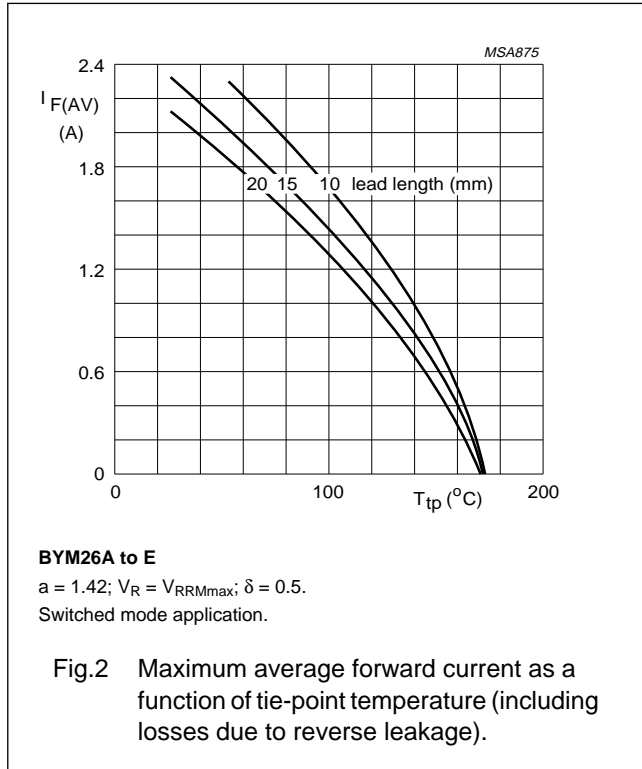
Note

1. Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer $\geq 40 \mu\text{m}$, see Fig.19. For more information please refer to the 'General Part of Handbook SC01'.

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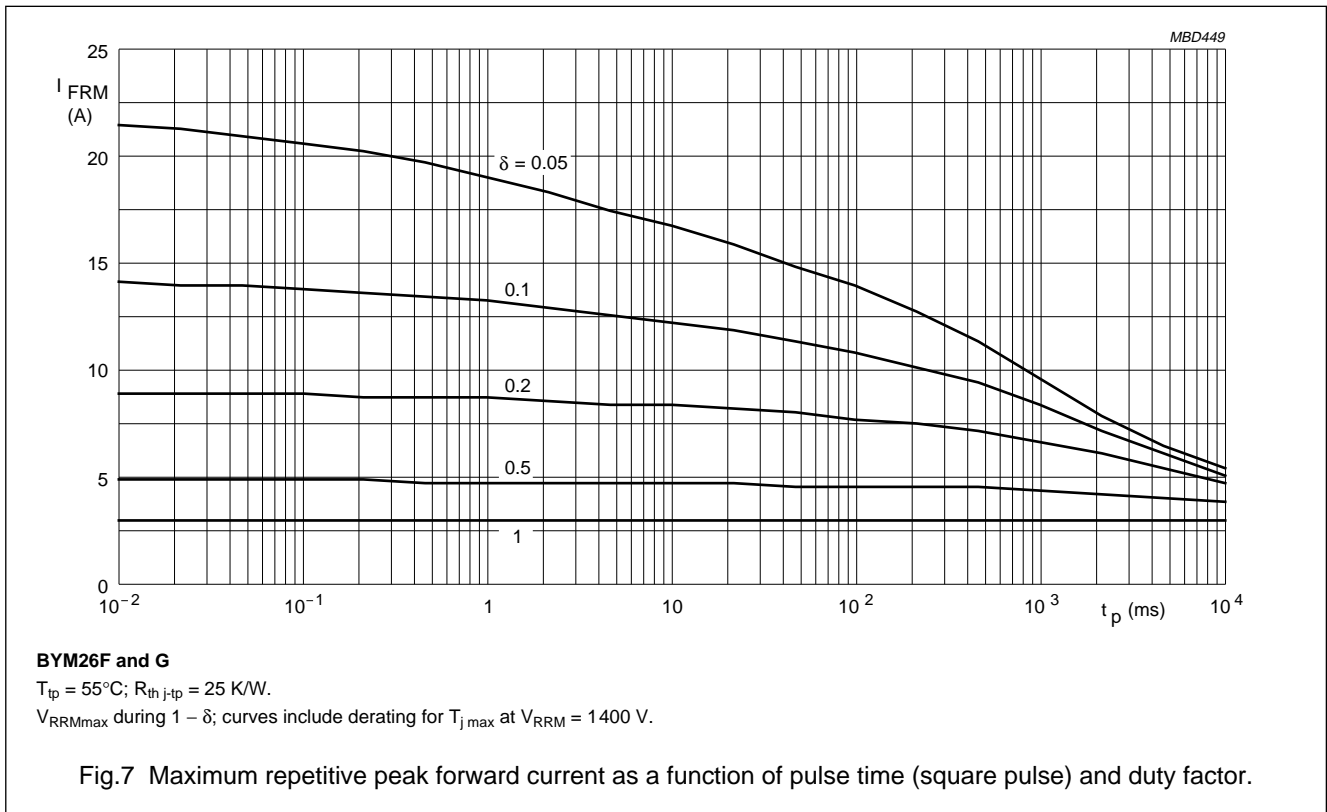
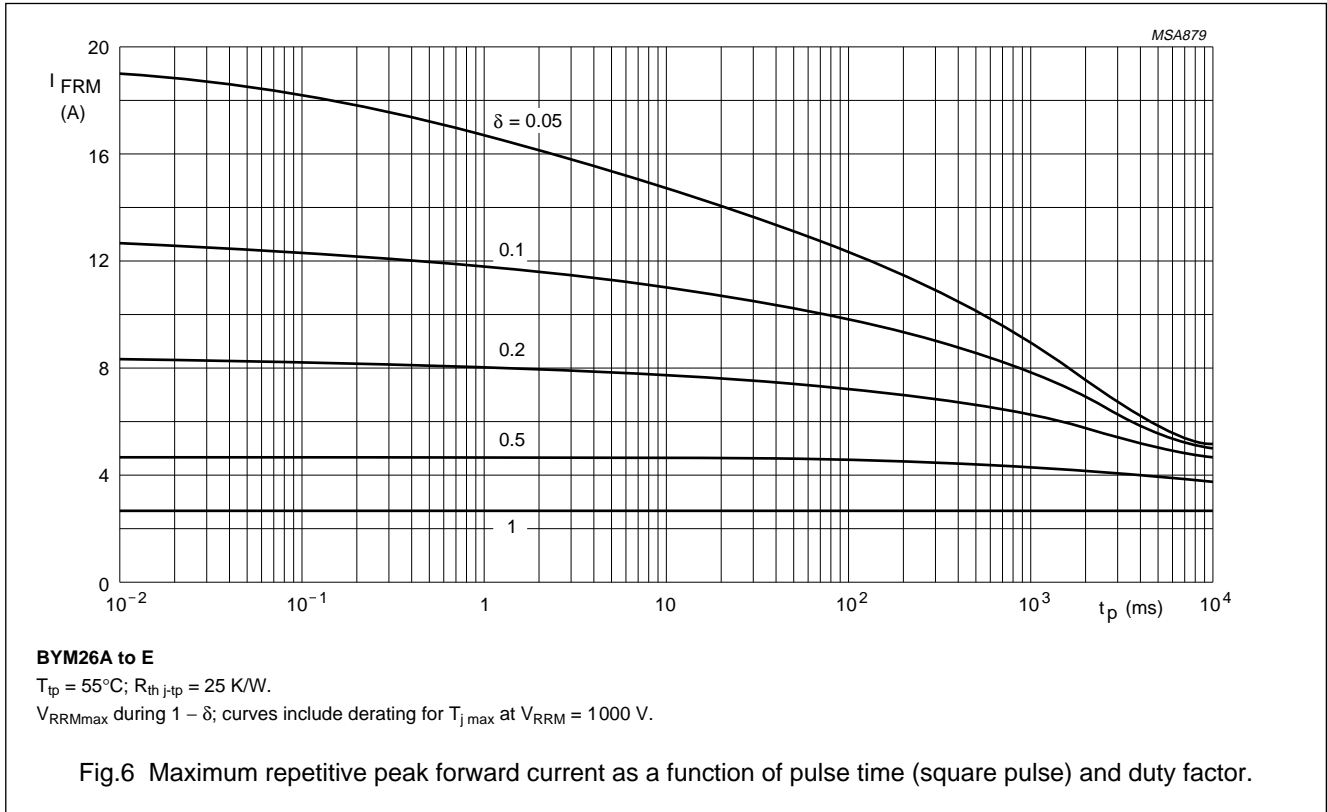
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GRAPHICAL DATA



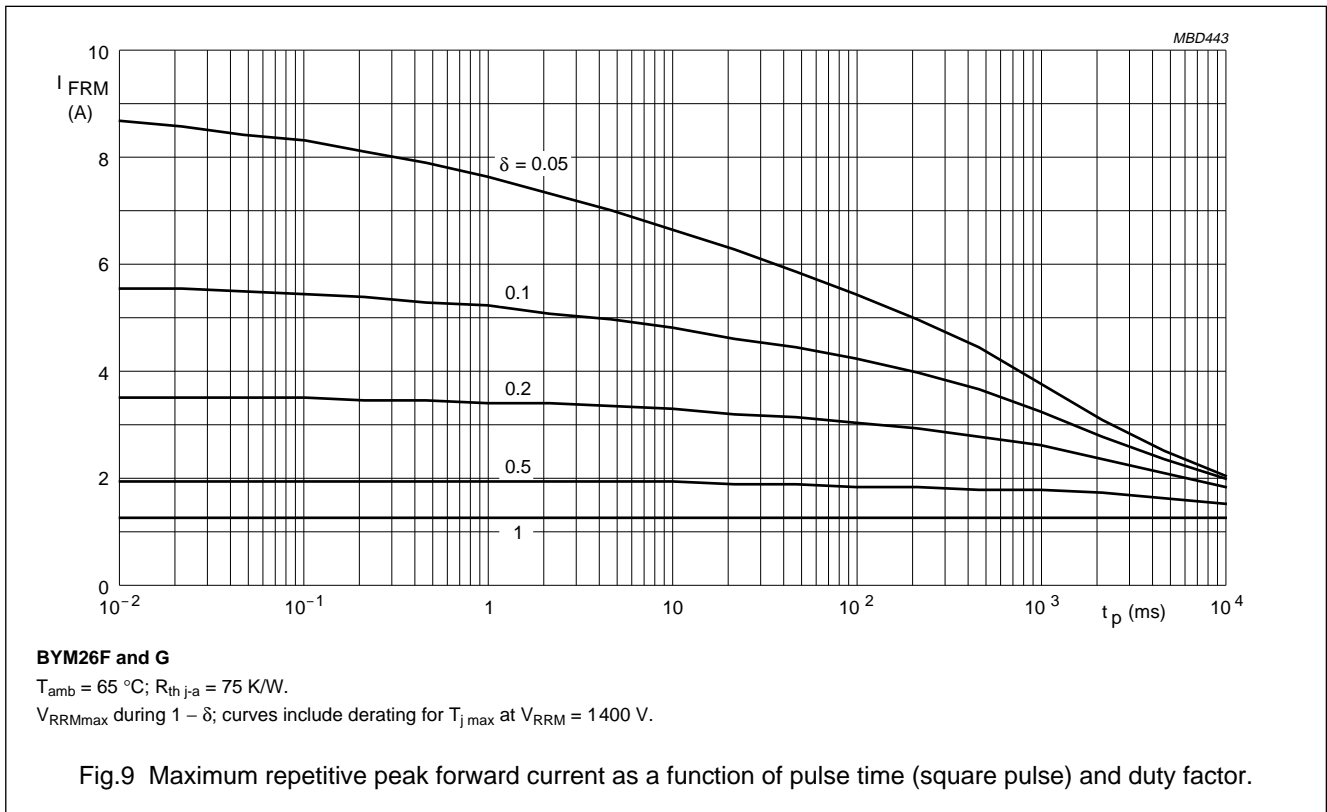
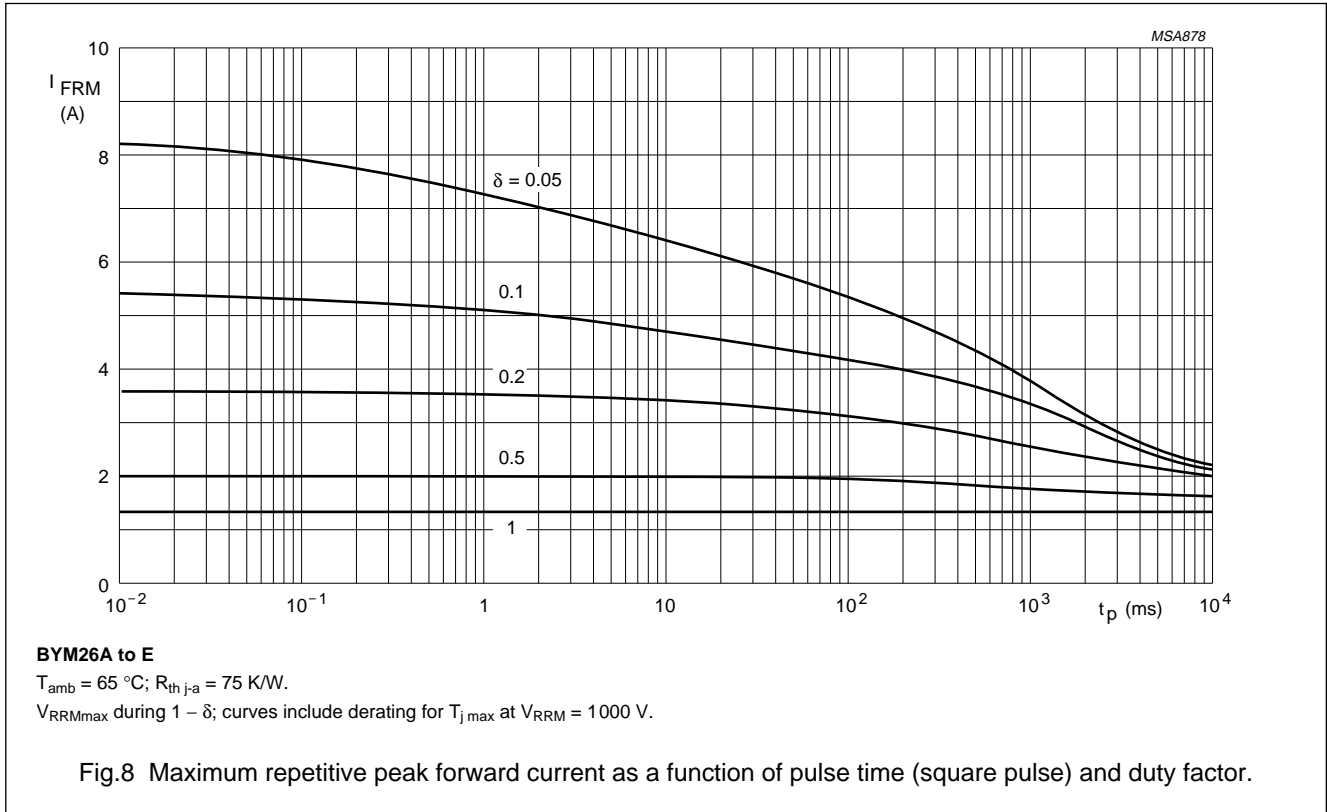
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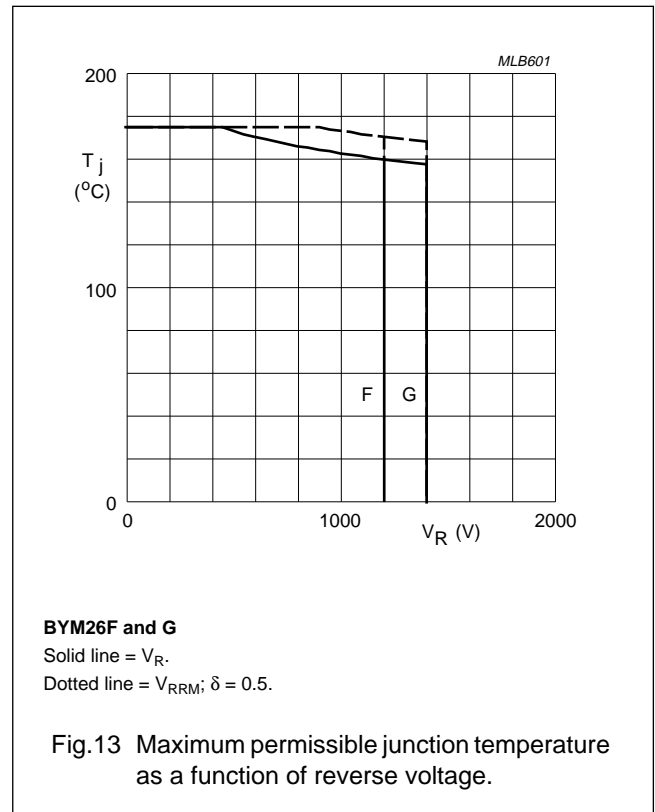
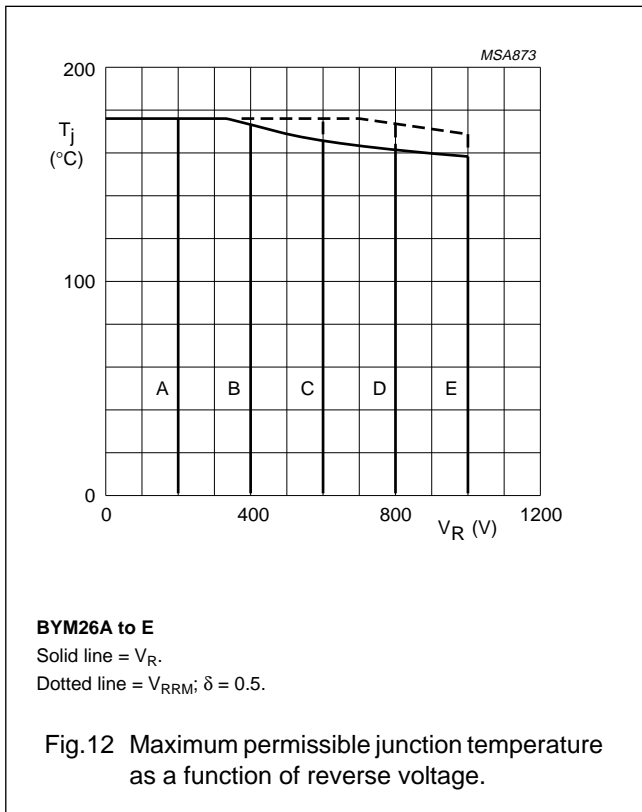
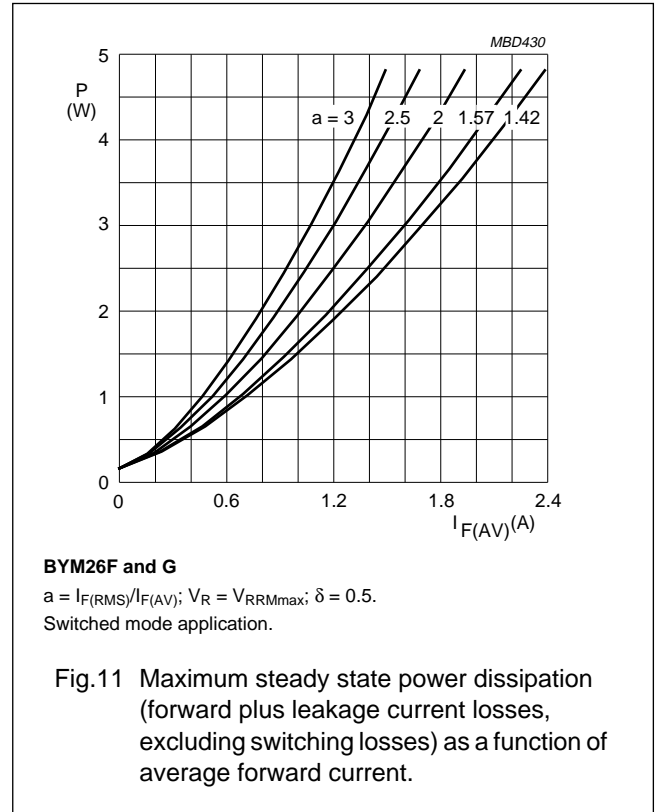
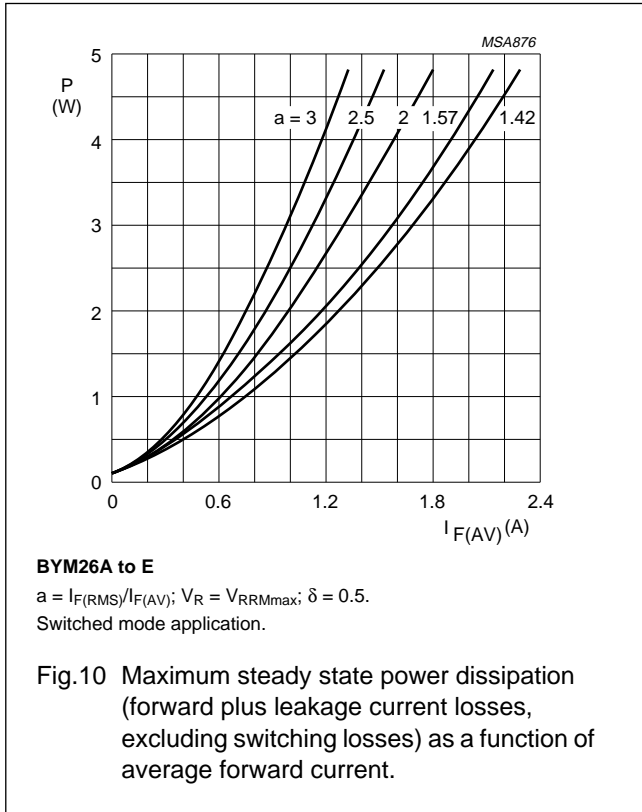
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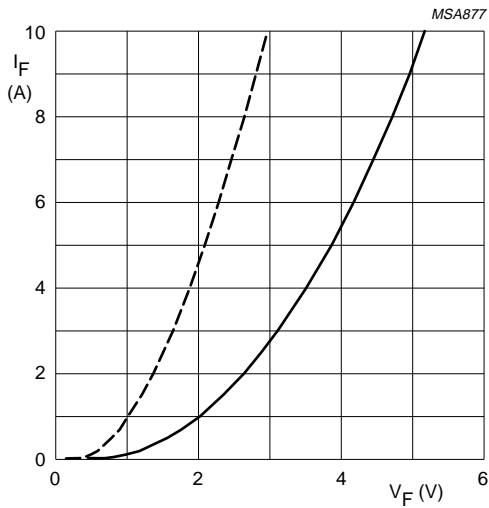
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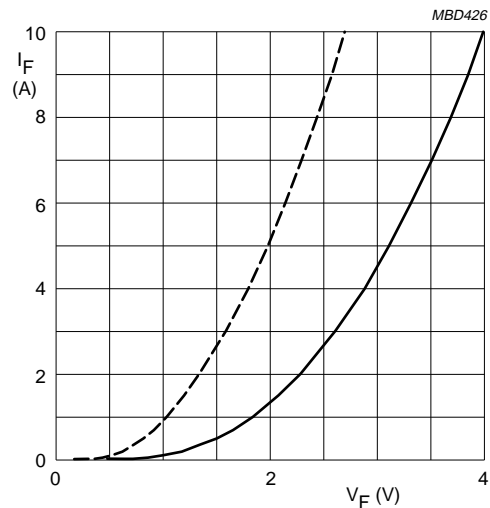
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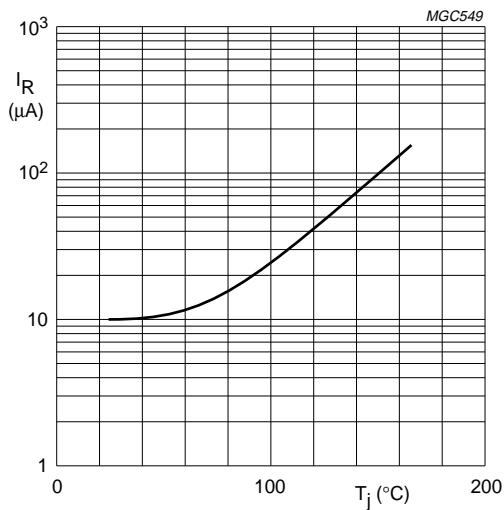
BYM26A to E
Dotted line: $T_j = 175\text{ }^\circ\text{C}$.
Solid line: $T_j = 25\text{ }^\circ\text{C}$.

Fig.14 Forward current as a function of forward voltage; maximum values.



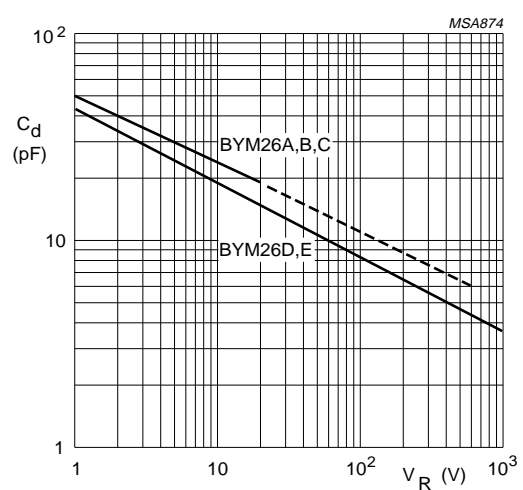
BYM26F and G
Dotted line: $T_j = 175\text{ }^\circ\text{C}$.
Solid line: $T_j = 25\text{ }^\circ\text{C}$.

Fig.15 Forward current as a function of forward voltage; maximum values.



$V_R = V_{RRMmax}$.

Fig.16 Reverse current as a function of junction temperature; maximum values.

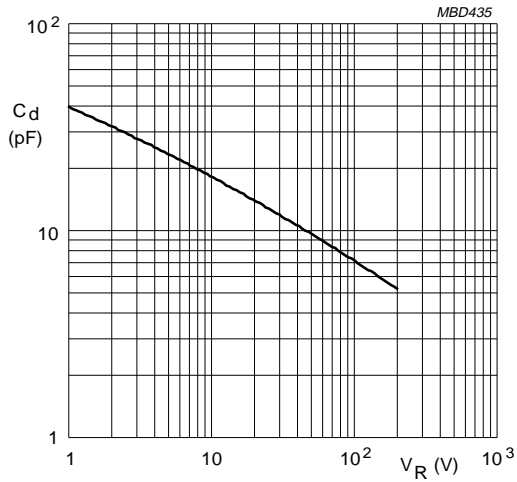


BYM26A to E
 $f = 1\text{ MHz}$; $T_j = 25\text{ }^\circ\text{C}$.

Fig.17 Diode capacitance as a function of reverse voltage; typical values.

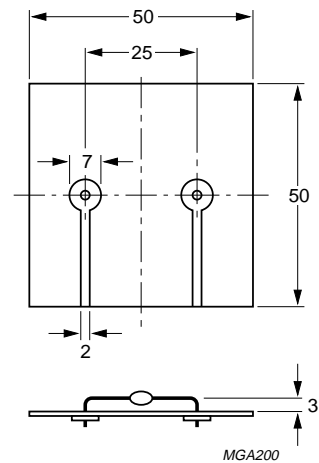
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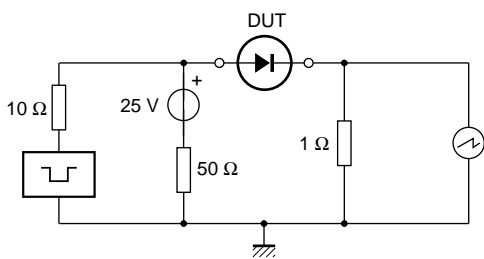
BYM26F and G
f = 1 MHz; T_j = 25 °C.

Fig.18 Diode capacitance as a function of reverse voltage; typical values.



Dimensions in mm.

Fig.19 Device mounted on a printed-circuit board.



Input impedance oscilloscope: 1 MΩ, 22 pF; t_r ≤ 7 ns.
Source impedance: 50 Ω; t_r ≤ 15 ns.

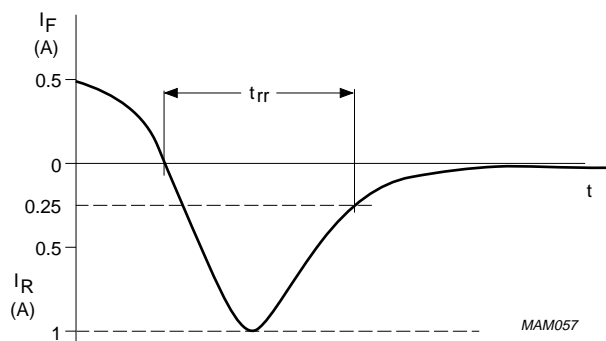
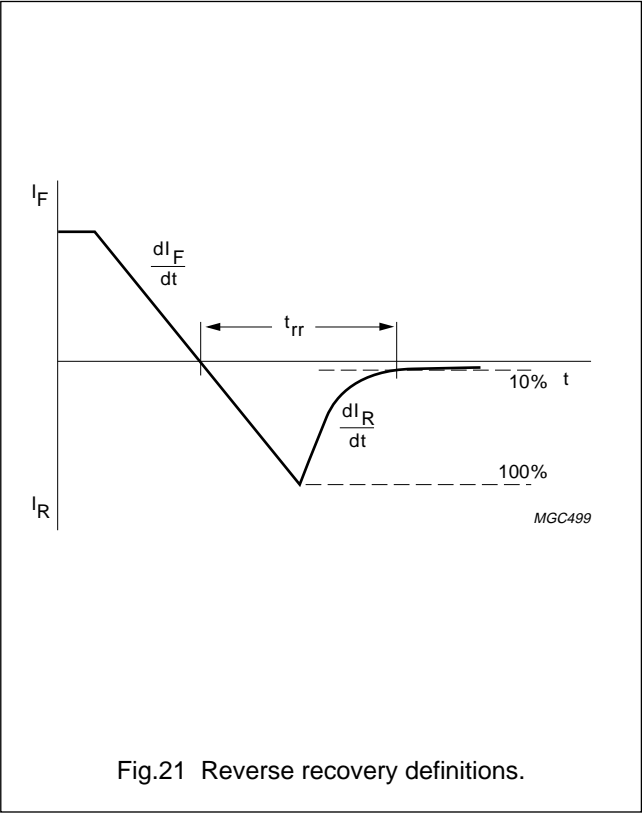


Fig.20 Test circuit and reverse recovery time waveform and definition.

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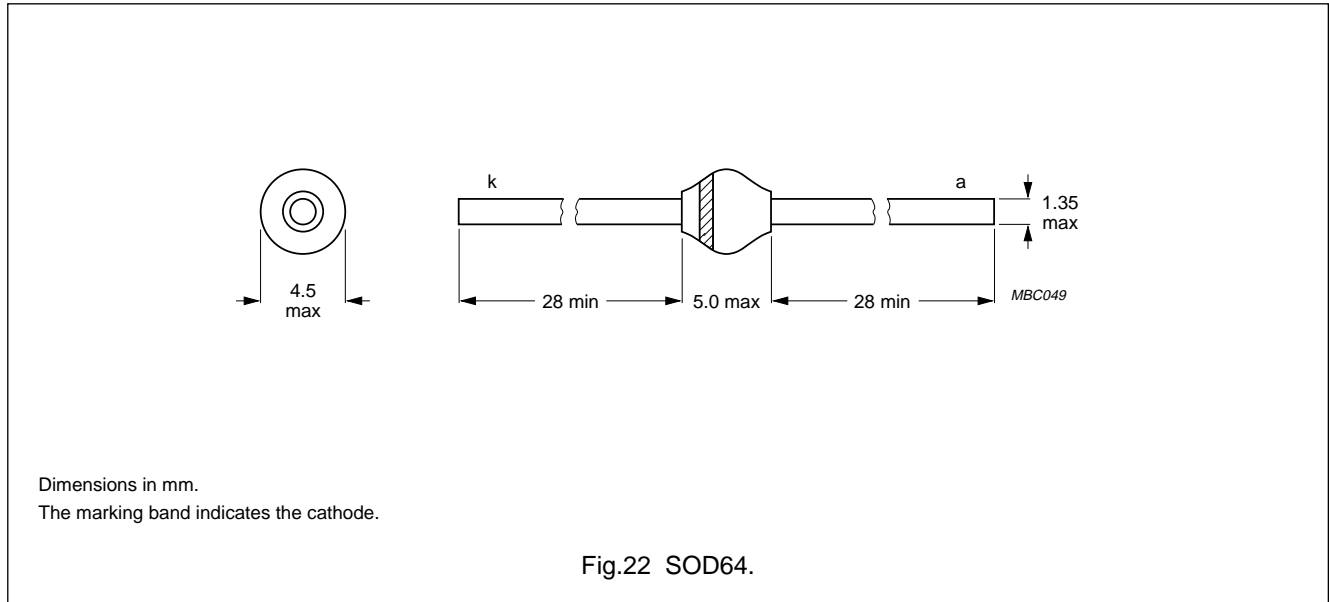
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PACKAGE OUTLINE



DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.